

**140V PNP SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT223**

**Features**

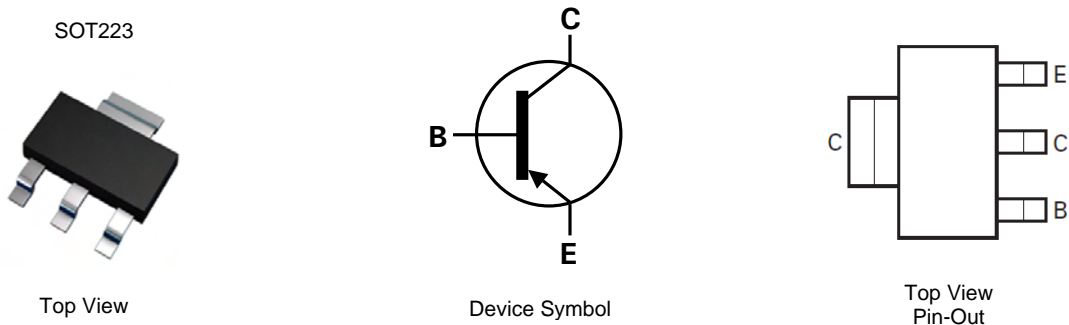
- $BV_{CEO} > -140V$
- $I_C = -4A$  high Continuous Collector Current
- $I_{CM} = -10A$  Peak Pulse Current
- Low saturation voltage  $V_{CE(sat)} < -120mV @ I_C = -1A$
- $R_{SAT} = 92m\Omega$  for a low equivalent On-Resistance
- $h_{FE}$  specified up to -10A for a high gain hold up
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (approximate)

**Application**

- Motor driving
- Line switching
- High side switches
- Subscriber line interface cards (SLIC)

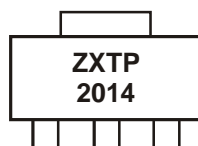


**Ordering Information** (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP2014GTA	ZXTP2014	7	12	1,000
ZXTP2014GTC	ZXTP2014	13	12	4,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com>.

**Marking Information**



ZXTP2014 = Product Type Marking Code

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CB0</sub>	-180	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-140	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	I <sub>C</sub>	-4	A
Peak Pulse Current	I <sub>CM</sub>	-10	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

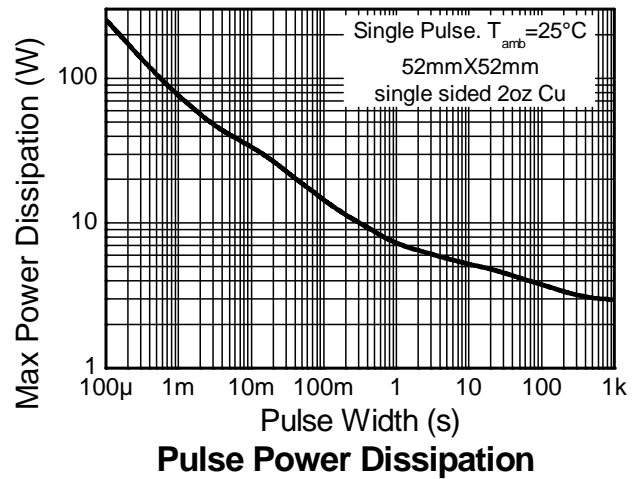
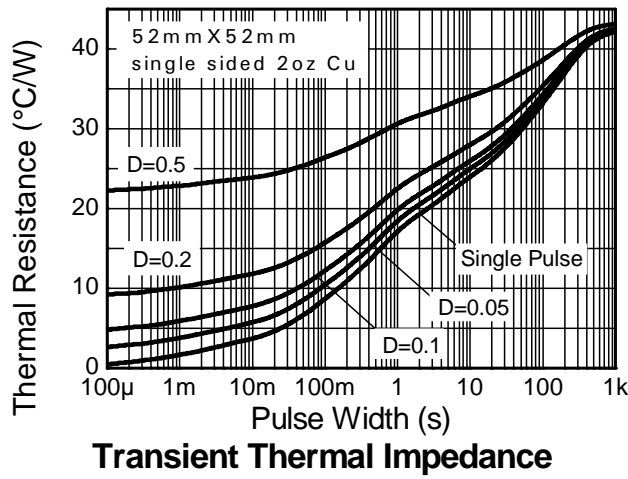
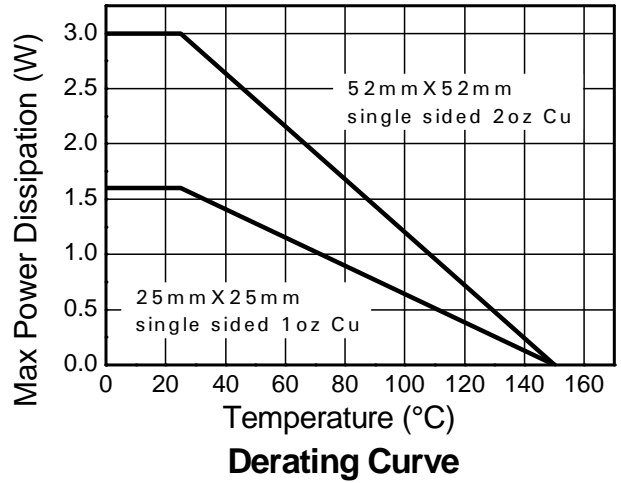
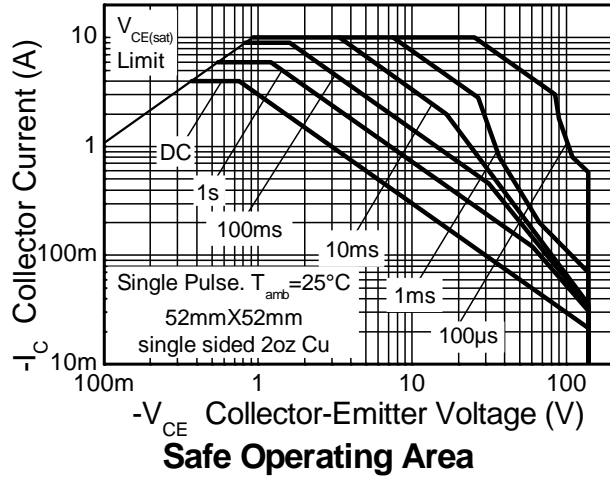
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	3.0	W
Linear derating factor		24	mW/°C
Power Dissipation (Note 6)	P <sub>D</sub>	1.6	W
Linear derating factor		12.8	mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>θJA</sub>	42	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>θJA</sub>	78	°C/W
Thermal Resistance Junction to Lead (Note 7)	R <sub>θJL</sub>	10.48	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**ESD Ratings** (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

- Notes:
5. For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
  6. Same as note (5), except the device is surface mounted on 25mm x 25mm with 1oz copper.
  7. Thermal resistance from junction to solder-point (at the end of the collector lead).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Thermal Characteristics and Derating Information**

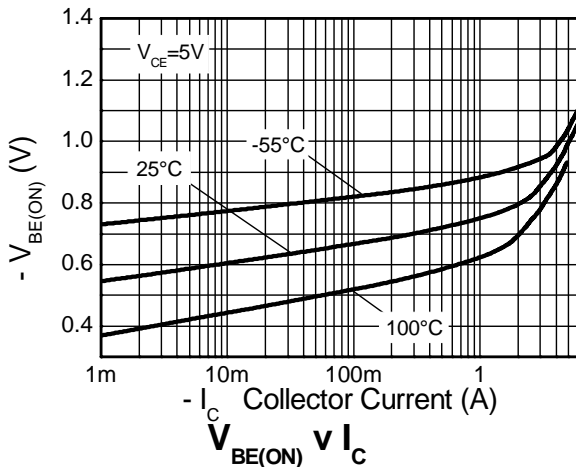
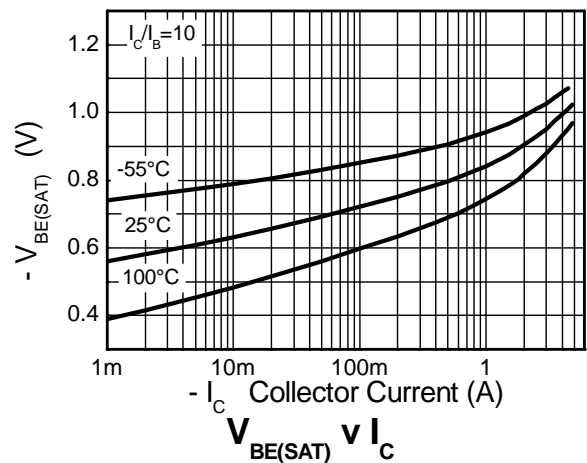
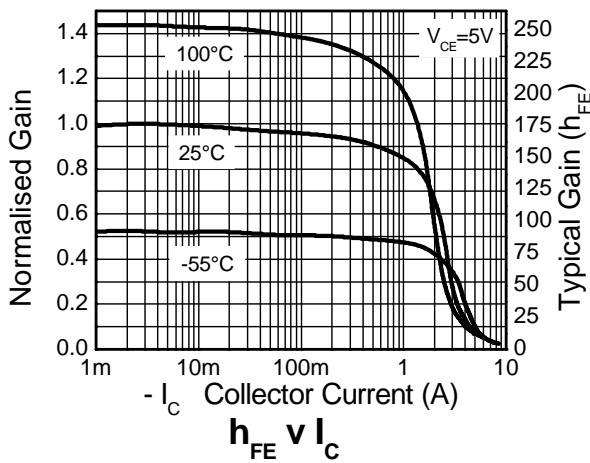
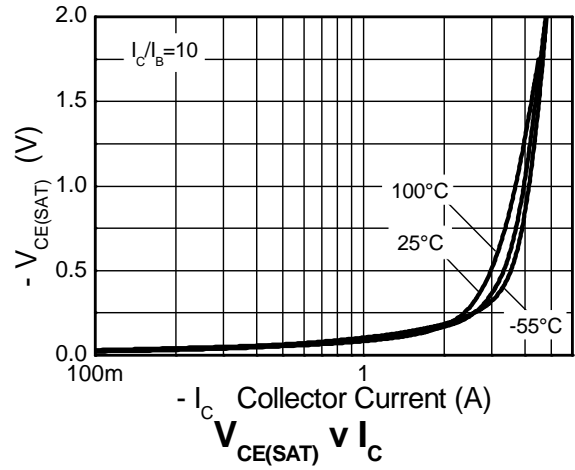
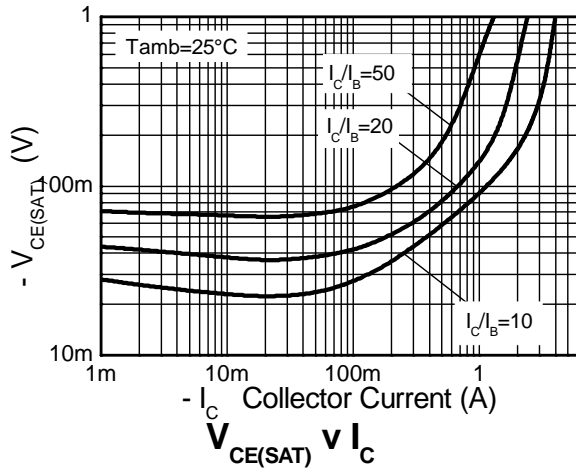


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CB0</sub>	-180	-200	-	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CER</sub>	-180	-200	-	V	I <sub>C</sub> = -1μA, R <sub>B</sub> ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-140	-160	-	V	I <sub>C</sub> = -1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.3	-	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CB0</sub>	-	< -1	-20	nA	V <sub>CB</sub> = -150V
		-	-	-500	nA	V <sub>CB</sub> = -150V, T <sub>A</sub> = +100°C
Collector Cutoff Current	I <sub>CER</sub> R ≤ 1kΩ	-	< -1	-20	nA	V <sub>CB</sub> = -150V
		-	-	-500	nA	V <sub>CB</sub> = -150V, T <sub>A</sub> = +100°C
Emitter Cutoff Current	I <sub>EBO</sub>	-	< -1	-10	nA	V <sub>EB</sub> = -6V
DC current transfer Static ratio (Note 9)	h <sub>FE</sub>	100	225	-	-	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -5V
		100	200	300		I <sub>C</sub> = -1A, V <sub>CE</sub> = -5V
		45	100	-		I <sub>C</sub> = -3A, V <sub>CE</sub> = -5V
		-	5	-		I <sub>C</sub> = -10A, V <sub>CE</sub> = -5V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	-	-40	-60	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA
		-	-55	-80		I <sub>C</sub> = -0.5A, I <sub>B</sub> = -50mA
		-	-85	-120		I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
		-	-275	-360		I <sub>C</sub> = -3A, I <sub>B</sub> = -300mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	-	-940	-1040	mV	I <sub>C</sub> = -3A, I <sub>B</sub> = -300mA
Base-Emitter Turn-on Voltage (Note 9)	V <sub>BE(on)</sub>	-	-830	-930	mV	I <sub>C</sub> = -3A, V <sub>CE</sub> = -5V
Transitional Frequency (Note 9)	f <sub>T</sub>	-	120	-	MHz	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V, f = 50MHz
Output capacitance	C <sub>obo</sub>	-	33	-	pF	V <sub>CB</sub> = -10V, f = 1MHz
Switching Time	t <sub>ON</sub>	-	42	-	ns	V <sub>CC</sub> = -50V, I <sub>C</sub> = -1A, I <sub>B1</sub> = -I <sub>B2</sub> = -100mA
	t <sub>OFF</sub>	-	636	-		

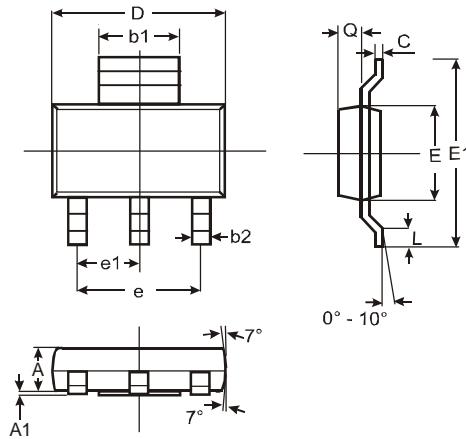
Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



### Package Outline Dimensions

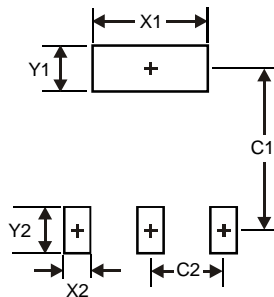
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

### Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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